



#### 4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

### **Product Summary**

VRWM (Max)	IPP (Max)	Ст (тур)
60V	2A	10pF

### **Description**

The D60V0L4B10LP is a high-performance device suitable for protecting four high speed I/Os. These devices are assembled in U-DFN2510-10 and U-DFN2510-10 (Type CJ) packages. They have high ESD surge capability and low capacitance.

### **Applications**

 Typically used at chip-on-glass (COG) panels, VBus protections, LCD televisions, set-top boxes

#### **Features**

- IEC 61000-4-2 (ESD):±8kV (Contact)
- IEC 61000-4-2 (ESD):±8kV (Air)
- 4 Channel of ESD Protection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

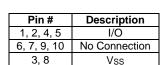
#### **Mechanical Data**

- Package: U-DFN2510-10
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals:

Sites 1 and 2: NiPdAu over Copper Leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208 @4 Site 3: Matte Tin over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3

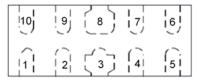
• Weight: 0.038 grams (Approximate)

Sites 1 and 2: U-DFN2510-10

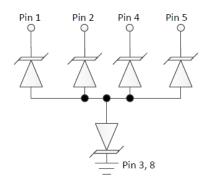


10	9	8	7	6
1	2	3	4	5

Site 3: U-DFN2510-10 (Type CJ)



Pin Description (Top View)



Schematic Diagram

### **Ordering Information** (Note 4)

Part Number	Packago	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
Fait Nullibei	Package	Warking	Reel Size (Illulies)	rape widin (min)	Qty.	Carrier
D60V0L4B10LP-7	U-DFN2510-10	QD4	7	8	3,000	Tape & Reel
D60V0L4B10LP-7	U-DFN2510-10 (Type CJ)	QD4	7	8	3,000	Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**

Sites 1 and 3

QD4 YM

QD4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: K = 2023) M = Month (ex: 9 = September) Site 2

QD4 YWX

QD4 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023)

W = Week

(ex: a=Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U=Monday)

Date Code Key for YM

Bate Code Hey for												
Year	2017	-	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	Е	-	K	L	М	Ν	Р	R	S	Т	U	V
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Date Code Key for YWX

Year	2017	-	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	7	-	3	4	5	6	7	8	9	0	1	2

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	X	Υ	Z

### **Maximum Ratings** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
ESD Contact Discharge	VESD	8	kV	Standard IEC 61000-4-2
Peak Pulse Current	IPP	2	Α	Standard IEC 61000-4-5,8/20µs
Operating Temperature Range	Top	-40 to +125	°C	_
Storage Temperature Range	Тsтg	-65 to +150	°C	_

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	PD	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	Reja	360	°C/W
Thermal Resistance, Junction to Case Typical (Note 5)	Rejc	220	°C/W

# **Electrical Characteristics** (@TA = +25°C, unless otherwise specified.)

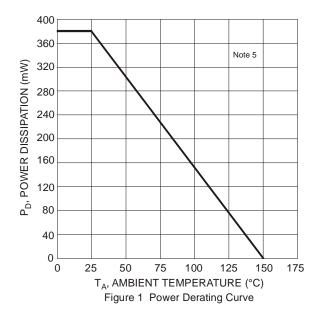
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	VRWM	_	_	60	V	_
Channel Leakage Current (Note 6)	I <sub>RM</sub>	_	_	100	nA	V <sub>RWM</sub> = 60V
Clamping Voltage, Positive Transients	VcL	_	115	125	V	$I_{PP} = 2A$ , $t_{PP} = 8/20\mu s$
Breakdown Voltage	V <sub>BR</sub>	65	75	85	V	I <sub>R</sub> = 1mA
Channel Input Capacitance	Ст	_	10	12	pF	V <sub>R</sub> = 0V, f = 1MHz

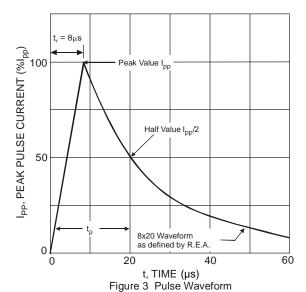
Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

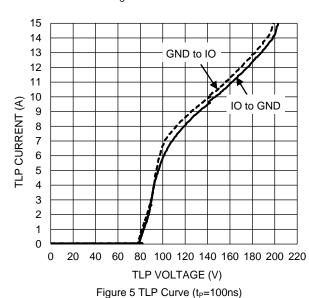
<sup>6.</sup> Short duration pulse test used to minimize self-heating effect.

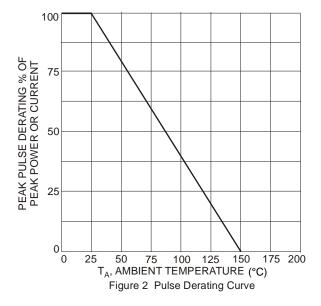


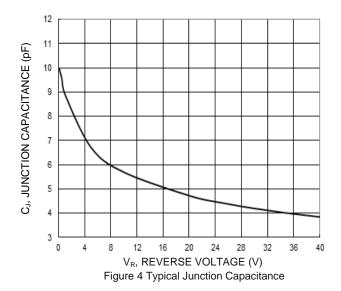












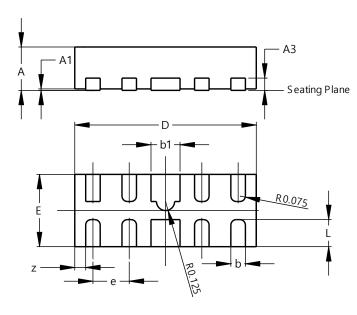
rigule 5 TEP Curve (tp=100fls)



# **Package Outline Dimensions**

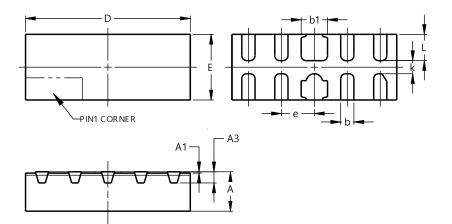
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### Sites 1 and 2: U-DFN2510-10



ı	U-DFN2510-10							
Dim	Min	Max	Тур					
Α	0.545	0.605	0.575					
A1	0.00	0.05	0.03					
A3	-	-	0.13					
b	0.15	0.25	0.20					
b1	0.35	0.45	0.40					
D	2.450	2.575	2.500					
е	-	-	0.50					
Е	0.950	1.075	1.000					
L	0.325	0.425	0.375					
Z	-	-	0.150					
All D	imensi	ons in	mm					

Site 3: U-DFN2510-10 (Type CJ)



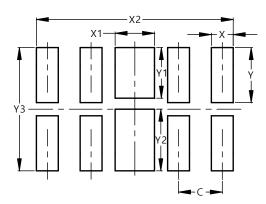
U-DFN2510-10									
(Type CJ)									
Dim	Dim Min Max Typ								
Α	0.545	0.605	-						
A1	0.00	0.05	-						
A3	0.	152RE	F						
b	0.150	0.250							
b1	0.350	0.450							
D	2.450	2.575							
Е	0.950	1.075	-						
е			0.500						
Е	0.950	1.075	1.000						
L 0.350 0.450									
k	k 0.200REF								
All D	imensi	ons in	mm						



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### All Sites: U-DFN2510-10 and U-DFN2510-10 (Type CJ)



Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Υ	0.625
Y1	0.575
Y2	0.700
Y3	1.400



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